NSN 5961-01-347-8506

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View Online at https://aerobasegroup.com/nsn/5961-01-347-8506 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.562 inches and 0.860 inches Overall Width: 1.050 inches **Function For Which Designed:** Switching **End Application:** Radar, search, an/sps-48; emory s. Land class as; nimitz class cvn; kidd class ddg; tarawa class lha; 2m/ate microminiauture automatic test equipment; virginia class cgn (41); wasp class lhd; forrestal class cv **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204ae **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 drain to source voltage and 500.0 drain to gate voltage **Current Rating Per Characteristic:** 12.00 amperes drain current **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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